

BC846A-BC848C

NPN SURFACE MOUNT SMALL SIGNAL TRANSISTOR IN SOT23

Features

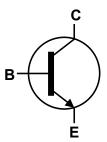
- Ideally Suited for Automatic Insertion
- Complementary PNP Types Available (BC856 BC858)
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

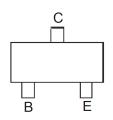
- Case: SOT23
- Case material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.008 grams (Approximate)







Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

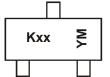
Product	Compliance	Compliance Marking		Quantity per reel
BC846A-7-F	AEC-Q101	K1Q	7	3,000
BC846AQ-7-F	Automotive	K1Q	7	3,000
BC846B-7-F	AEC-Q101	K1R / C1R	7	3,000
BC846BQ-7-F	Automotive	K1R	7	3,000
BC846B-13-F	AEC-Q101	K1R / C1R	13	10,000
BC846BQ-13-F	Automotive	K1R	13	10,000
BC847A-7-F	AEC-Q101	K1Q	7	3,000
BC847AQ-7-F	Automotive	K1Q	7	3,000
BC847A-13-F	AEC-Q101	K1Q	13	10,000
BC847B-7-F	AEC-Q101	K1R / C1R	7	3,000
BC847BQ-7-F	Automotive	K1R	7	3,000

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC847B-13-F	AEC-Q101	K1R / C1R	13	10,000
BC847C-7-F	AEC-Q101	K1M	7	3,000
BC847CQ-7-F	Automotive	K1M	7	3,000
BC847C-13-F	AEC-Q101	K1M	13	10,000
BC848A-7-F	AEC-Q101	K1Q	7	3,000
BC848B-7-F	AEC-Q101	K1R	7	3,000
BC848B-13-F	AEC-Q101	K1R	13	10,000
BC848C-7-F	AEC-Q101	K1M	7	3,000
BC848CQ-7-F	Automotive	K1M	7	3,000

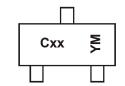
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http"//www.diodes.com/products/packages.html

Marking Information



K = SAT (Shanghai Assembly / Test site) xx = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)



C = CAT (Chengdu Assembly / Test site) xx = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)

Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016	i	2017
Code	X		Υ	Z		Α	В		С	D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	g Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteri	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V _{CBO}	50	V
_	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V _{CEO}	45	V
-	BC848		30	
Emitter Base Valtage	BC846, BC847	V	6.0	V
Emitter-Base Voltage	BC848	V _{EBO}	5.0] v
Continuous Collector Current		I _C	100	mA
Peak Collector Current		I _{CM}	200	mA
Peak Emitter Current		I _{EM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	_	310	mW
	(Note 7)	P _D	350	IIIVV
Thermal Decistance, Junction to Ambient	(Note 6)	0	403	00/14/
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction to Leads (Note 8)		$R_{\theta JL}$	350	°C/W
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-65 to +150	°C

ESD Ratings (Note 9)

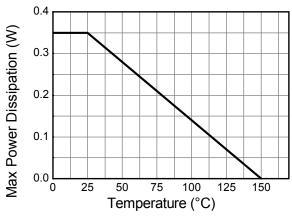
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

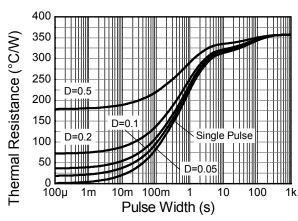
Notes:

- 6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 7. For the device mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 8. Thermal resistance from junction to solder-point (at the end of the leads).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



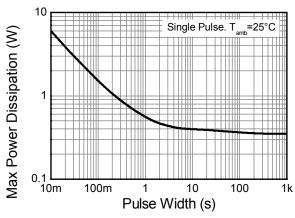
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic				Min	Тур	Max	Unit	Test Condition	
		BC846	Symbol	80	-				
Collector-Base Breakdown V	oltage	BC847	BV _{CBO}	50	_	_	V	$I_C = 10\mu A$	
	•	BC848		30					
Callantan Fraittan Brankday	\/alta=a	BC846		65	_	_			
Collector-Emitter Breakdown Voltage (Note 10)		BC847	BV _{CEO}	45			V	I _C = 10mA	
(Note 10)		BC848		30					
Emitter-Base Breakdown Voltage BC846 / BC847		BC846 / BC847	D\/	6	_		V	1 - 4	
Emilier-Base Breakdown vo	nage	BC848	BV _{EBO}	5			V	I _E = 1μA	
Collector Cutoff Current			lone			_	μA	V _{CB} = 40V	
Collector Cutoff Current			Ісво	_	_	_	μΑ	$V_{CB} = 30V, T_A = +150$ °C	
		BC846			_	15		V _{CE} = 80V	
Collector Emitter Cutoff Curr	ent	BC847	ICES	_		15	nA	V _{CE} = 50V	
		BC848				15		V _{CE} = 30V	
0	BC846A / E	3C847A / BC848A			200		_		
Small Signal Current Gain (Note 10)	BC846B / E	3C847B / BC848B	h _{fe}	_	330	_			
(Note 10)	BC847	7C / BC848C	1 .0		600			_	
Innut Impedance		3C847A / BC848A	h _{ie}		2.7		kΩ		
Input Impedance (Note 10)	BC846B / E	3C847B / BC848B		_	4.5	_			
(Note 10)	BC847	7C / BC848C			8.7			$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
Output Admittance	BC846A / BC847A / BC848A BC846B / BC847B / BC848B BC847C / BC848C		h _{oe}		18		μS	f=1.0kHz	
(Note 10)				_	30	_			
(14010-10)					60]	
Reverse Voltage Transfer	BC846A / BC847A / BC848A BC846B / BC847B / BC848B BC847C / BC848C				1.5x10 ⁻⁴	_	_		
Ratio (Note 10)			h _{re}	_	2x10 ⁻⁴				
rtatio (rtote 10)					3x10 ⁻⁴				
		3C847A / BC848A		110	180	220			
DC Current Gain (Note 10)	BC846B / BC847B / BC848B		h_{FE}	200	290	450	_	$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
		7C / BC848C		420	520	800			
Collector-Emitter Saturation	Voltage		V _{CE(sat)}		90	250	mV	$I_C = 10mA$, $I_B = 0.5mA$	
(Note 10)			V CE(sat)		200	600	1117	$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Turn-On Voltag	ro(Noto 10)		V	580	660	700	mV	$I_C = 2mA$, $V_{CE} = 5V$	
Base-Emilier Turri-Ori Voltag	je(Note 10)		V _{BE(on)}	ı		770	IIIV	I_C = 10mA, V_{CE} = 5V	
Base-Emitter Saturation Voltage(Note 10)			\/·		700		mV	$I_C = 10mA$, $I_B = 0.5mA$	
			V _{BE(sat)}		900	_	IIIV	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$	
Output Capacitance		C _{obo}		3	_	pF	$V_{CB} = 10V, f = 1.0MHz$		
Transition Frequency		f _T	100	300	_	MHz	$V_{CE} = 5V, I_{C} = 10mA,$ f = 100MHz		
Noise Figure			NF	_	2	10	dB	V_{CE} =5V, I_{C} =200 μ A R_{S} =2k Ω , f=1kHz Δ f=200Hz	

Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

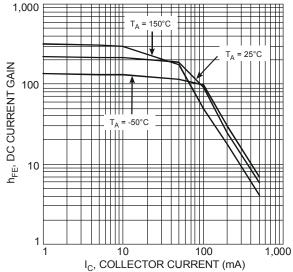
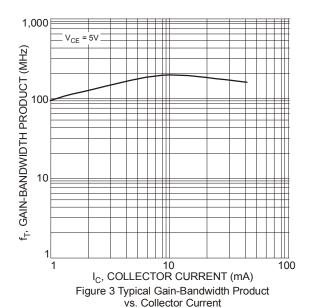


Figure 1 Typical DC Current Gain vs. Collector Current



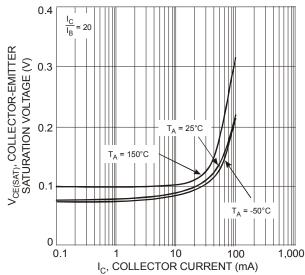
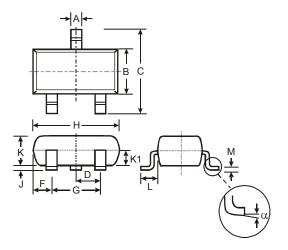


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current



Package Outline Dimensions

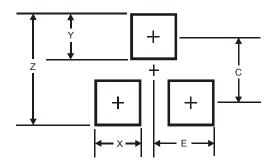
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.903	1.10	1.00				
K1	-	-	0.400				
L	0.45	0.61	0.55				
М	0.085	0.18	0.11				
α	0°	8°	-				
All	Dimens	ions in	mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
Е	1.35



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